

PMGD290UCEA

20 / 20 V, 725 / 500 mA N/P-channel Trench MOSFET

28 March 2014 Product data sheet

1. General description

Complementary N/P-channel enhancement mode Field-Effect Transistor (FET) in a very small SOT363 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Very fast switching
- Trench MOSFET technology
- 2 kV ESD protection
- AEC-Q101 qualified

3. Applications

- · Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits
- Automotive applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
TR1 (N-cha	nnel), Static characteristic	es					
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_{D} = 500 mA; T_{j} = 25 °C		-	290	380	mΩ
TR2 (P-cha	nnel), Static characteristic	es					
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I_{D} = -400 mA; T_{j} = 25 °C		-	670	850	mΩ
TR1 (N-cha	nnel)		'	·			
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V_{GS}	gate-source voltage	_		-8	-	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	-	725	mA
TR2 (P-cha	nnel)		'	'			,
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V



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20 / 20 V, 725 / 500 mA N/P-channel Trench MOSFET

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{GS}	gate-source voltage			-8	_	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-500	mA

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².

Pinning information

Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1	<u>654</u>	D1 D2
2	G1	gate TR1		
3	D2	drain TR2	0	G1 $G2$ $G2$
4	S2	source TR2	∐1 ∐2 ∐3	
5	G2	gate TR2	TSSOP6 (SOT363)	
6	D1	drain TR1		S1 S2 017aaa262

Ordering information

Ordering information Table 3.

<u> </u>						
Type number	Package					
	Name	Description	Version			
PMGD290UCEA	TSSOP6	plastic surface-mounted package; 6 leads	SOT363			

Marking

Table 4. Marking codes

Table II III III III III III III III III II					
Type number	Marking code				
	[1]				
PMGD290UCEA	YD%				

^{[1] % =} placeholder for manufacturing site code

Limiting values

Limiting values

PMGD290UCEA

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
TR1 (N-channel)						
V_{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V_{GS}	gate-source voltage			-8	8	V

Symbol	Parameter	Conditions		Min	Max	Unit
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	725	mA
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	450	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10$ μs		-	3	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	280	mW
			[1]	-	320	mW
		T _{sp} = 25 °C		-	990	mW
TR1 (N-cha	nnel), Source-drain diode					
Is	source current	T _{amb} = 25 °C	[1]	-	370	mA
TR1 N-char	nnel), ESD maximum rating		'	'		
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V
TR2 (P-cha	nnel)					
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-500	mA
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-320	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10$ μs		-	-2	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	280	mW
			[1]	-	320	mW
		T _{sp} = 25 °C		-	990	mW
TR2 (P-cha	nnel), Source-drain diode		'	,	,	
I _S	source current	T _{amb} = 25 °C	[1]	-	-370	mA
TR2 (P-cha	nnel), ESD maximum rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V
Per device	'		'	,	'	
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	445	mW
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
G						

^[1]

Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm². Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard

Measured between all pins.

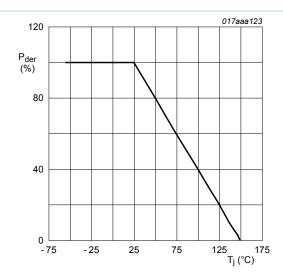


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

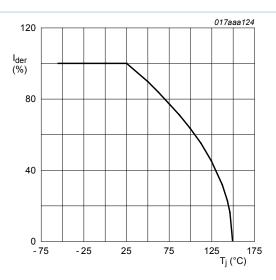


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

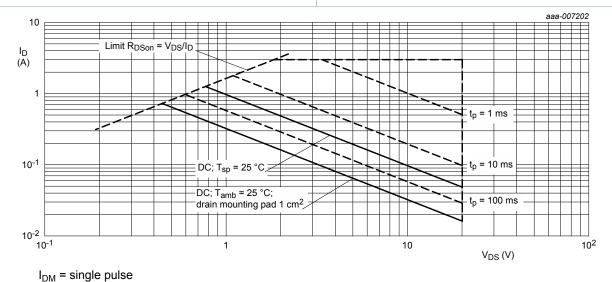


Fig. 3. TR1 (N-channel): safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

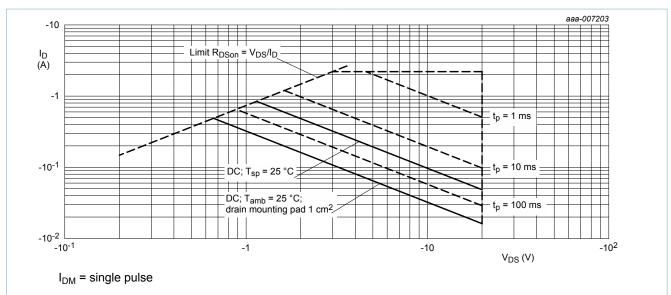


Fig. 4. TR2 (P-channel): safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
TR1 (N-cha	nnel)		,				,
R _{th(j-a)}	thermal resistance	in free air	[1]	-	390	445	K/W
from junction to ambient		[2]	-	340	390	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	130	K/W
TR2 (P-cha	nnel)		,				
R _{th(j-a)}	thermal resistance	in free air	[1]	-	390	445	K/W
	from junction to ambient		[2]	-	340	390	K/W
$R_{\text{th(j-sp)}}$	thermal resistance from junction to solder point			-	-	130	K/W
Per device			1				,
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	300	K/W

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

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^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².

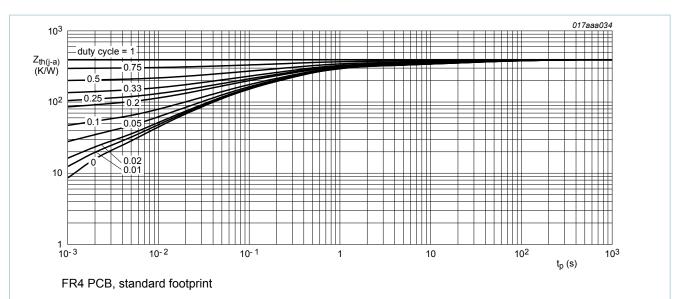
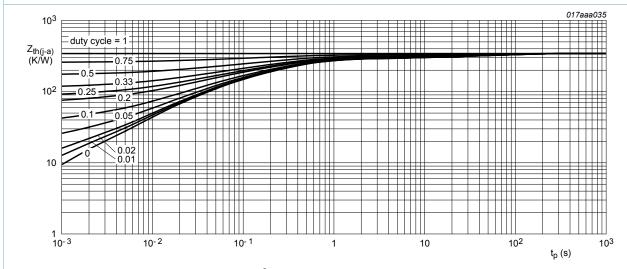


Fig. 5. TR1: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 1 cm².

Fig. 6. TR1: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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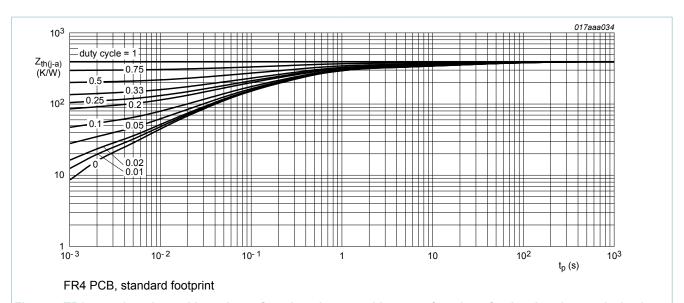


Fig. 7. TR2: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

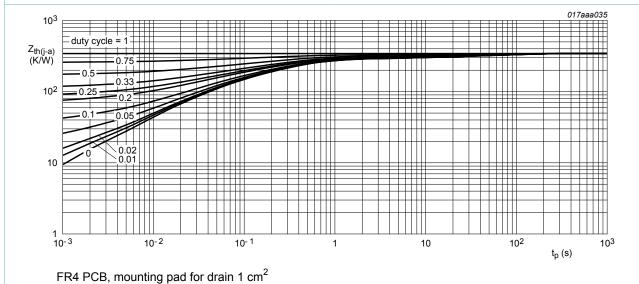


Fig. 8. TR2: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7 Characteristics

Table 7.	Characteristics	Conditions	B. d. i	Torre	Mess	1124
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	annel), Static characteristic					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.5	0.75	0.95	V
I _{DSS}	drain leakage current	V_{DS} = 20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	10	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; -40 °C < T _j < 150 °C	-	-	10	μA
		V _{GS} = -8 V; V _{DS} = 0 V; -40 °C < T _j < 150 °C	-	-	-10	μA
R _{DSon}	drain-source on-state	V _{GS} = 4.5 V; I _D = 500 mA; T _j = 25 °C	-	290	380	mΩ
resistance	V _{GS} = 4.5 V; I _D = 500 mA; T _j = 150 °C	-	460	610	mΩ	
		V _{GS} = 2.5 V; I _D = 200 mA; T _j = 25 °C	-	420	620	mΩ
		V _{GS} = 1.8 V; I _D = 10 mA; T _j = 25 °C	-	0.6	1.1	Ω
9 _{fs}	transfer conductance	V_{DS} = 10 V; I_{D} = 200 mA; T_{j} = 25 °C	-	1.6	-	S
TR1 (N-ch	annel), Dynamic characteris	stics	1			
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I_{D} = 500 mA; V_{GS} = 4.5 V;	-	0.45	0.68	nC
Q_{GS}	gate-source charge	T _j = 25 °C	-	0.15	-	nC
Q_{GD}	gate-drain charge		-	0.15	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; f = 1 MHz; V _{GS} = 0 V;	-	55	83	pF
C _{oss}	output capacitance	T _j = 25 °C	-	15	-	pF
C _{rss}	reverse transfer capacitance		-	7	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; R_L = 250 Ω ; V_{GS} = 4.5 V;	-	6	12	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time		-	86	172	ns
t _f	fall time		-	31	-	ns
TR1 (N-ch	annel), Source-drain diode	characteristics	l .			
V _{SD}	source-drain voltage	I_S = 300 mA; V_{GS} = 0 V; T_j = 25 °C	0.48	0.77	1.2	V
TR2 (P-ch	annel), Static characteristic	s	I	1	1	
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{GSth}	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-0.5	-0.8	-1.3	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	-10	μΑ
I _{GSS} gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; -40 °C < T _j < 150 °C	-	-	10	μA	
		V _{GS} = -8 V; V _{DS} = 0 V; -40 °C < T _j < 150 °C	-	-	-10	μA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I_D = -400 mA; T_j = 25 °C	-	670	850	mΩ
resistance	V _{GS} = -4.5 V; I _D = -400 mA; T _j = 150 °C	-	1.1	1.4	Ω	
	V_{GS} = -2.5 V; I_D = -200 mA; T_j = 25 °C	-	1.2	1.5	Ω	
		V_{GS} = -1.8 V; I_D = -10 mA; T_j = 25 °C	-	1.8	2.8	Ω
9fs	transfer conductance	V _{DS} = -10 V; I _D = -200 mA; T _j = 25 °C	-	610	-	mS
TR2 (P-cha	annel), Dynamic characteri	stics				
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -400 mA;	-	0.76	1.14	nC
Q_{GS}	gate-source charge	V _{GS} = -4.5 V; T _j = 25 °C	-	0.28	-	nC
Q_{GD}	gate-drain charge		-	0.18	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	58	87	pF
C _{oss}	output capacitance	T _j = 25 °C	-	21	-	pF
C _{rss}	reverse transfer capacitance		-	12	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; R_L = 250 Ω ; V_{GS} = -4.5 V;	-	18	36	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega$; $T_j = 25 ^{\circ}C$	-	30	-	ns
t _{d(off)}	turn-off delay time		-	80	160	ns
t _f	fall time		-	72	-	ns
TR2 (P-cha	annel), Source-drain diode	characteristics			1	
V _{SD}	source-drain voltage	I_S = -300 mA; V_{GS} = 0 V; T_i = 25 °C	-0.48	-0.84	-1.2	V

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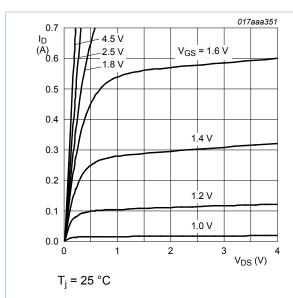
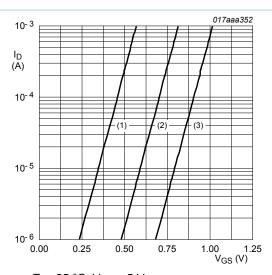


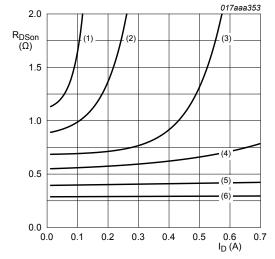
Fig. 9. TR1; Output characteristics: drain current as a function of drain-source voltage; typical values



 T_i = 25 °C; V_{DS} = 5 V

- (1) minimum values
- (2) typical values
- (3) maximum values

Fig. 10. TR1; Sub-threshold drain current as a function of gate-source voltage



T_i = 25 °C

(1) $V_{GS} = 1.3 \text{ V}$

(2) $V_{GS} = 1.4 \text{ V}$

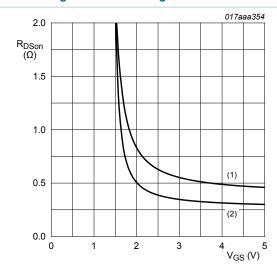
 $(3) V_{GS} = 1.6 V$

 $(4) V_{GS} = 1.8 V$

 $(5) V_{GS} = 2.5 V$

 $(6) V_{GS} = 4.5 V$

Fig. 11. TR1; Drain-source on-state resistance as a function of drain current; typical values

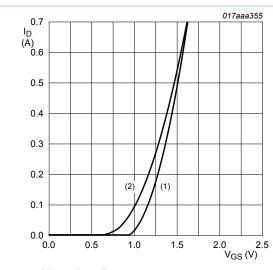


 $I_D = 400 \text{ mA}$

(1) $T_i = 150 \, ^{\circ}C$

(2) $T_i = 25 \,^{\circ}C$

Fig. 12. TR1; Drain-source on-state resistance as a function of gate-source voltage; typical values



$$V_{DS} > I_D \times R_{DSon}$$

(1)
$$T_i = 25 \,^{\circ}C$$

(2)
$$T_i = 150 \, ^{\circ}\text{C}$$

Fig. 13. TR1; Transfer characteristics: drain current as a function of gate-source voltage; typical values

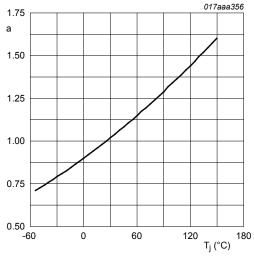
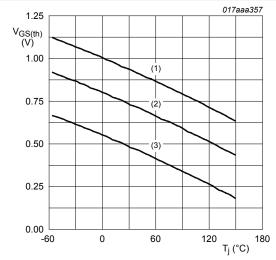


Fig. 14. TR1; Normalized drain-source on-state resistance as a function of junction temperature; typical values

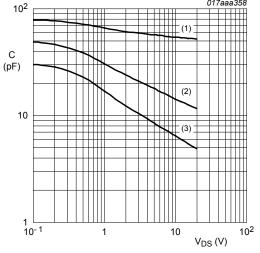
$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



 I_D = 0.25 mA; V_{DS} = V_{GS}

- (1) maximum values
- (2) typical values
- (3) minimum values

Fig. 15. TR1; Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

- (1) C_{iss}
- (2) C_{oss}
- (3) C_{rss}

Fig. 16. TR1; Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

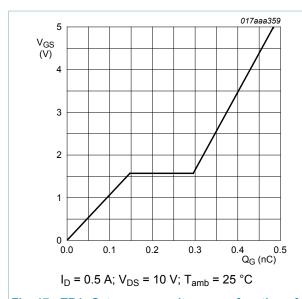


Fig. 17. TR1; Gate-source voltage as a function of gate charge; typical values

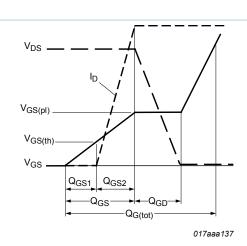
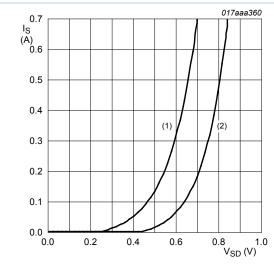


Fig. 18. Gate charge waveform definitions



 $V_{GS} = 0 V$ (1) $T_j = 150 \,^{\circ}C$ (2) $T_i = 25 \,^{\circ}C$

Fig. 19. TR1; Source current as a function of sourcedrain voltage; typical values

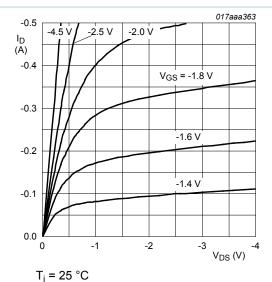
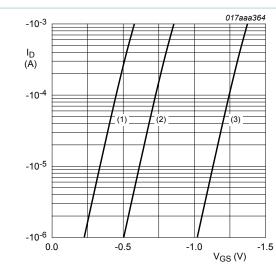


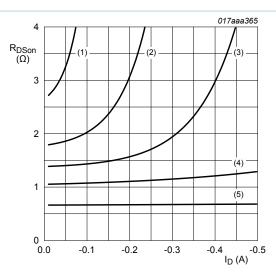
Fig. 20. TR2; Output characteristics: drain current as a function of drain-source voltage; typical values



$$T_i$$
 = 25 °C; V_{DS} = -5 V

- (1) minimum values
- (2) typical values
- (3) maximum values

Fig. 21. TR2; Sub-threshold drain current as a function of gate-source voltage



$$(1) V_{GS} = -1.5 V$$

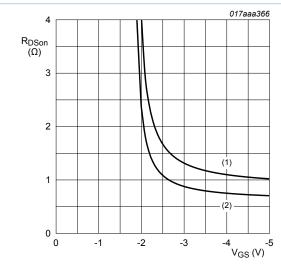
(2)
$$V_{GS} = -1.8 \text{ V}$$

$$(3) V_{GS} = -2.0 V$$

$$(4) V_{GS} = -2.5 V$$

$$(5) V_{GS} = -4.5 V$$

Fig. 22. TR2; Drain-source on-state resistance as a function of drain current; typical values

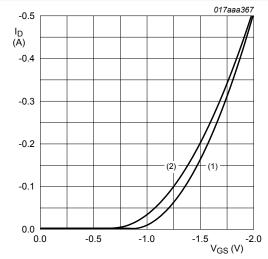


 $I_D = -400 \text{ mA}$

(1) $T_i = 150 \, ^{\circ}C$

(2) $T_i = 25$ °C

Fig. 23. TR2; Drain-source on-state resistance as a function of gate-source voltage; typical values



 $V_{DS} > I_D \times R_{DSon}$ (1) $T_i = 25 \, ^{\circ}C$

(2) $T_i = 150 \,^{\circ}\text{C}$

24 TP2: Transfer charac

Fig. 24. TR2; Transfer characteristics: drain current as a function of gate-source voltage; typical values

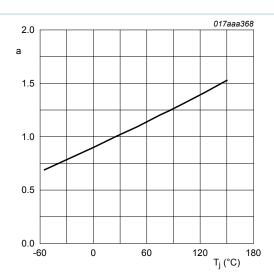
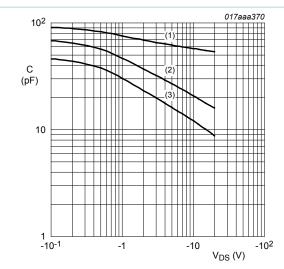


Fig. 25. TR2; Normalized drain-source on-state resistance as a function of ambient temperature; typical values

$$\mathbf{a} = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



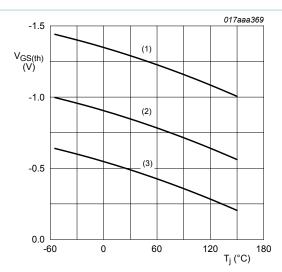
 $f = 1 MHz; V_{GS} = 0 V$

(1) C_{iss}

(2) C_{oss}

(3) C_{rss}

Fig. 27. TR2; Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



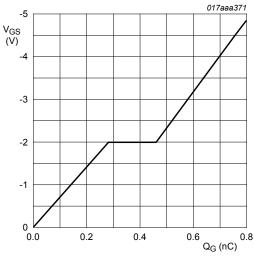
 I_D = -0.25 mA; V_{DS} = V_{GS}

(1) maximum values

(2) typical values

(3) minimum values

Fig. 26. TR2; Gate-source threshold voltage as a function of junction temperature



 $I_D = -0.4 \text{ A}; V_{DD} = -10 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$

Fig. 28. TR2; Gate-source voltage as a function of gate charge; typical values

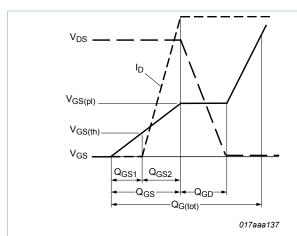


Fig. 29. Gate charge waveform definitions

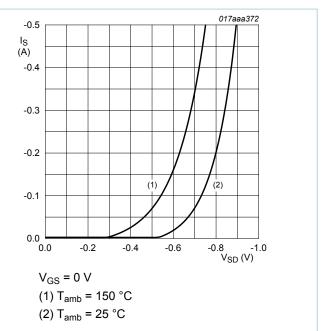
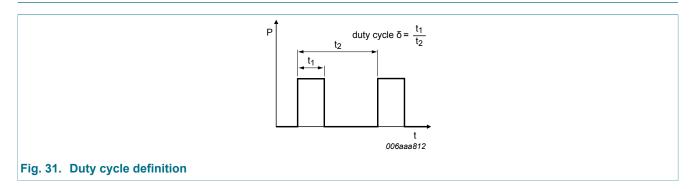


Fig. 30. TR2; Source current as a function of sourcedrain voltage; typical values

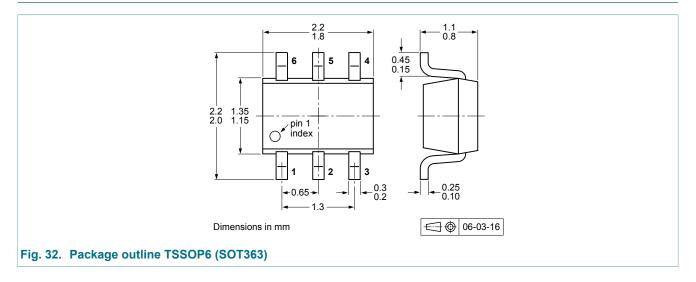
11. Test information



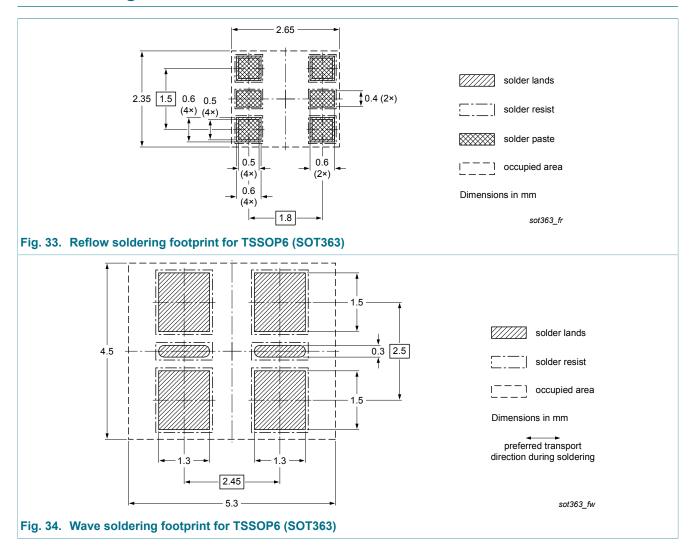
11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMGD290UCEA v.3	20140328	Product data sheet	-	PMGD290UCEA v.2		
Modifications:	Table 7: I _{GSS} param	Table 7: I _{GSS} parameter unit corrected				
PMGD290UCEA v.2	20130418	Product data sheet	-	PMGD290UCEA v.1		
PMGD290UCEA v.1	20130415	Product data sheet	-	-		

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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